Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

**Overall Length:** 

0.615 inches

Mounting Facility Quantity:

1

### Internal Configuration:

Junction contact

## **Mounting Method:**

Threaded stud

**Features Provided:** 

Hermetically sealed case

### **Overall Width Across Flats:**

Between 0.551 inches and 0.559 inches

**Thread Size:** 

0.250 inches

### Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

100.0 repetitive peak reverse voltage

## **Current Rating Per Characteristic:**

13.00 amperes forward current, total rms universal

## Power Rating Per Characteristic:

5.0 watts small-signal input power, common-collector blank

### Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

### **Special Features:**

Junction pattern arrangement: pnpn

### **Thread Series Designator:**

Unf

# Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

### Unit Of Measure:

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## Demilitarization:

No

Fiig:

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